

MB102M thru MB110M. Bridge Rectifiers

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MBM		Features							
		ROHS compliant							
		Glass passivated chip							
			High forward surge capability						
			Meet MSL level 1, per J-STD-020						
			LF maximum peak of 250 °C						
+ " _) ~ ~		 Solder dip 260 °C / 40S Component in accordance to BOHS 2002/05/EC 							
		 Component in accordance to ROHS 2002/95/EC and WEEE 2002/96/WC 							
		 UL recognition, file number E342874 							
Primary characteristics		Applications							
I _{F(AV)}	0.8A	Ideal	Ideal for ac-to-dc bridge full wave rectification suck as						
V _{RRM}	200V to 1000V	SMPS, home applianes, office equipment, indusrial							
I _{FSM}	35A	automation applicatios							
I _{RM}	5uA]							
V _{FM} at I _F =0.4A	1.0V	Mechanical data							
T _J max. 150 ℃			Case: MBM						
		Epoxy meets UL 94 V-0 flammability rating							
		Terminals: Tin plated leads.							
			 Polarity: As marked. Mounting Torque:10cm-kg(8.8 inches-lbs)max. 						
			 Recommended Torque:5.7 cm-kg(5 inches-lbs) 						
Maximum rating (Ta	$=25^{\circ}$ C unless othe				4401011	, in rig(o i		•)	
Maximum rating (Ta=25°C unless other Parameter		MBM							
		Sym	MB102M	MB104M	MB106M	MB108M	MB110M	Unit	
Max. repetitive peak reverse voltage		Vrrm	200	400	600	800	1000	V	
Max. RMS reverse voltage		V _{RMS}	140	280	420	560	700	V	
Max. DC blocking voltage		V _{DC}	200	400	600	800	1000	V	
Max. average forward current		I _{F(AV)}	0.8 A				А		
Non-repetitive peak forward surge current		I _{FSM}	35.0 A				A		
8.3ms single half-sine-wave									

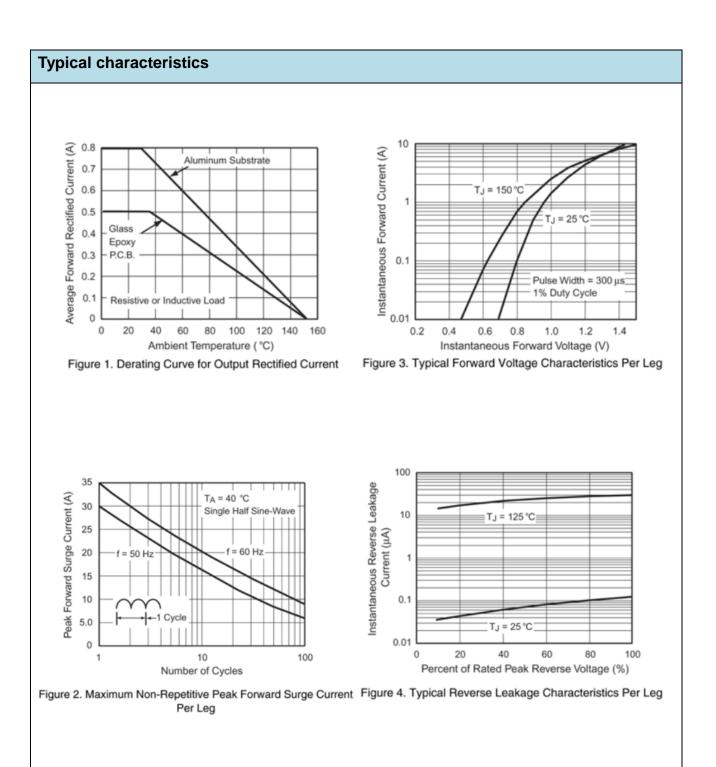
Parameter		Sym	MBM					I Imit
Farameter	MB102M		MB104M	MB106M	MB108M	MB110M	Unit	
Max. repetitive peak reverse voltage			200	400	600	800	1000	V
Max. RMS reverse voltage			140	280	420	560	700	V
Max. DC blocking voltage			200	400	600	800	1000	V
Max. average forward current			0.8					А
Non-repetitive peak forward surge current		IFSM	35.0					А
8.3ms single half-sine-wave		IFSM						
Rating for fusing,1ms $\leq t \leq 8.3$ ms		l ² t	5.0				A ² S	
Max. instantaneous forward voltage drop per diode		VFM	1 (0.4)					V
Max. instantaneous reverse current at	Ta=25 ⁰C		5					μA
rated DC blocking voltage	Ta=125 ⁰C	IRM	100					
Operating junction temperature		TJ	-55 ~ +150					°C
Storage temperature		T _{STG}	-55 ~ +150				°C	
Typical thermal resistance (Note1)		R J-A	70					°C/W
		R J-L	20				°C/W	

Notes

(1) On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3mm) pads

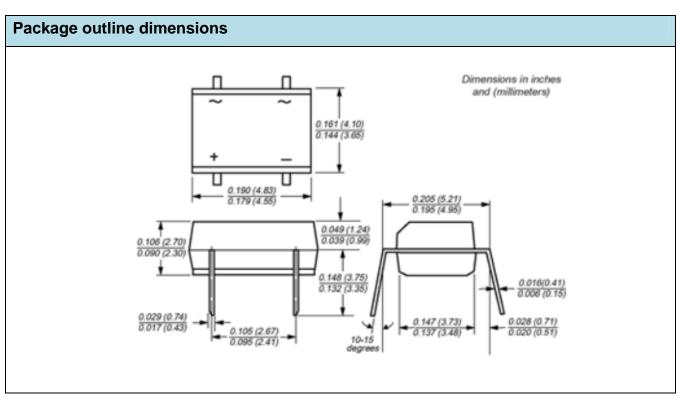


Ordering information (Example)								
PREFERRED	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
MB110M								





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